

# High efficiency quantum dot solar cells based on multiple exciton generation

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Date: May 26, 2010

## Overview



## **Timeline**

- Project start date: Feb. 2008
- Project end date: Jan. 2011
- Percent complete: 75%

## **Budget**

- Total project funding: \$1.1M
  - DOE share: \$0.9M
  - Contractor share: \$0.2M
- Funding received in FY09: \$0.3M
- Funding for FY10: \$0.3M

#### **Barriers**

- Barriers addressed
  - Device efficiency: demonstrate proof of concept to collect multiple exciton generated carriers

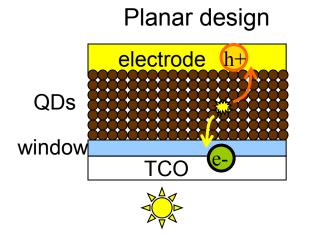
#### **Partners**

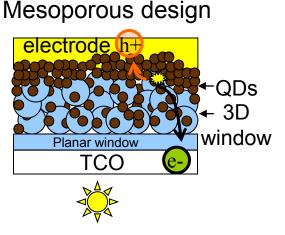
- U.C. Santa Cruz
  - Prof. Sue Carter
  - Prof. Glenn Alers
- Project lead: Alison Breeze

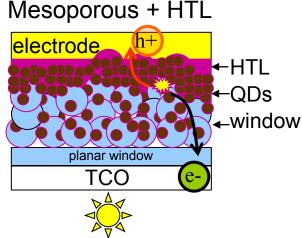
## Approach |



- Quantum dots: exchange long for short ligands for film formation and to improve charge transport
- Optimize charge generation and transport
  - Charge transfer: new ligands to tune charge transport
  - Recombination: improve passivation to eliminate traps
- Optimize energy level matching of QDs, window and electrode materials
- ALD hole transport layer (HTL) passivation and transport







## Challenges, Barriers or Problems



- Balancing trade-off between good charge transport against maintaining quantum confinement and MEG carrier generation
- successful integration of hole transport layer on top of QDs while maintaining quantum confinement properties

### Relevance



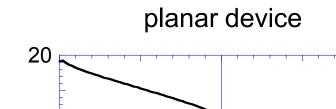
#### **Project Objectives:**

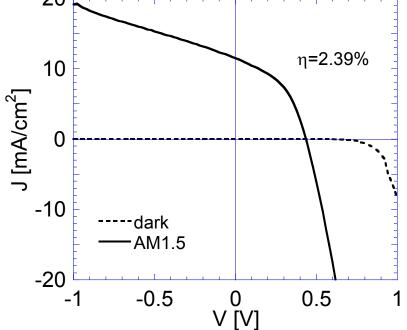
- Overall:
  - demonstrate that MEG in quantum dots can dramatically improve maximum efficiency obtainable in PV
  - Expand scientific field's understanding of quantum dot solar cell devices and factors limiting performance
- Year 2: milestone peak IQE=90% → achieved with peak IQE approaching 100%

Ability to harvest multiple exciton generated carriers will allow single junction solar cell efficiencies exceeding Shockley–Queisser limit of 31%

## **Device Performance**



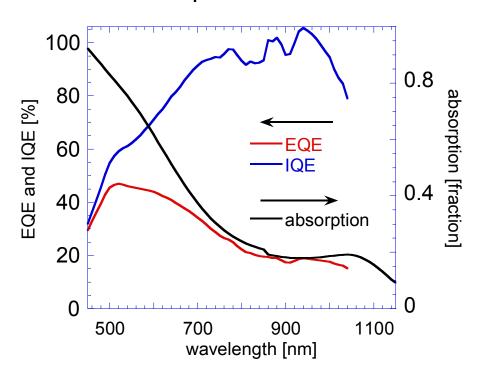




	V <sub>oc</sub> [V]	J <sub>sc</sub> [mA/cm <sup>2</sup> ]	ff [%]	η [%]
year 1	0.37	10.5	40	1.55
year 2	0.44	11.9	46	2.39

Improvements: deposition and ligand exchange

#### mesoporous device

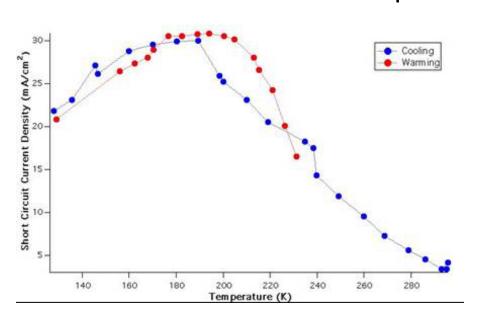


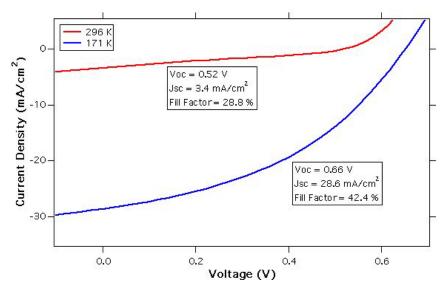
- IQE approaching 100% in near-IR
- Meets year 2 milestone
- IQE = EQE / absorption
- measurement error needs quantification

## Temperature Dependence



#### Mesoporous Device





#### Mechanism theories:

- Increased particle coupling via decreased interparticle distance
- Increased carrier lifetime

Stunning performance improvement for lower temperatures η~8% under 100mW/cm² xenon light source at 171K

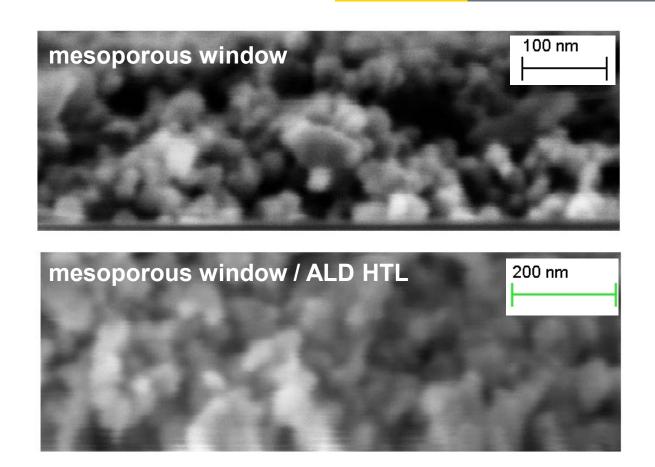
## Experiment summary and results



experiment	motivation	result	
shorter ligands	decrease QD spacing to improve transport	introduced counter-diode / charge suppresion feature, lower η	
secondary ligand passivation	decrease recombination	slightly lowered collection efficiency	
core/shell QD passivation	decrease recombination	improved passivation but interfered w/ transport; J <sub>sc</sub> loss	
vary window, electrode and QD energy levels	improve charge generation and collection	important factor requiring collective optimization	

## ALD of Hole Transport Layer





ALD HTL conformably coats mesoporous structure Integration into quantum dot solar cell architecture in progress

#### **Future Plans**



## Expand scientific understanding of QDSC functionality and nature of factors limiting device performance

- pinpoint efficiency increase mechanism for low temperature
- elucidate role of ligand on performance beyond interparticle spacing
- understand why short-ligand and additional passivation approaches had detrimental effects
- extensive material and device characterization

**Year 3 Milestone**: peak internal quantum efficiency IQE > 120%

Apply knowledge to engineer breakthrough performance at room temperature

## Collaborations



#### **U.C. Santa Cruz**

- Prof. Sue Carter and Prof. Glenn Alers research groups
- University laboratory and Advanced Studies Laboratory at NASA Ames Research Center
- relationship: sub-contractor within DOE Solar Program
- extensive collaboration

## Summary



- peak IQE approaching 100% in near-IR
- Temperature dependence demonstrates stunning efficiency increase to η~8% at low T
- Two avenues pursued to replicate performance at room temperature
  - increase particle coupling
  - improve surface defect passivation
- Expand material and device characterization

		peak IQE	peak IQE milestone	<u>η under am1.5</u>
yea	ar 1	79%	> 60%	1.56%
yea	ar 2	approaching 100%	> 90%	2.39%